MMBT918LT1G

VHF/UHF Transistor

NPN Silicon

Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	15	Vdc
Collector-Base Voltage	V _{CBO}	30	Vdc
Emitter-Base Voltage	V _{EBO}	3.0	Vdc
Collector Current – Continuous	Ι _C	50	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C	PD	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

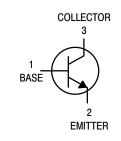
1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



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MARKING DIAGRAM



M3B = Device Code

M = Date Code*

= Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT918LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

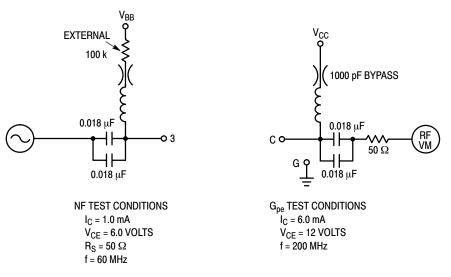
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

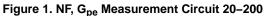
MMBT918LT1G

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage $(I_C = 3.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	15	_	Vdc
Collector-Base Breakdown Voltage ($I_c = 1.0 \ \mu Adc, I_E = 0$)	V _{(BR)CBO}	30	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	3.0	_	Vdc
Collector Cutoff Current ($V_{CB} = 15 \text{ Vdc}, I_E = 0$)	I _{CBO}	_	50	nAdc
ON CHARACTERISTICS				
DC Current Gain (I _C = 3.0 mAdc, V _{CE} = 1.0 Vdc)	h _{FE}	20	_	_
Collector – Emitter Saturation Voltage $(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$	V _{CE(sat)}	_	0.4	Vdc
Base – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$)	V _{BE(sat)}	_	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS			•	•
Current-Gain – Bandwidth Product ($I_C = 4.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	600	_	MHz
Output Capacitance ($V_{CB} = 0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$) ($V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$)	C _{obo}	-	3.0 1.7	pF
Input Capacitance (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz)	C _{ibo}	_	2.0	pF
Noise Figure (I _C = 1.0 mAdc, V _{CE} = 6.0 Vdc, R _S = 50 Ω , f = 60 MHz) (Figure 1)	NF	_	6.0	dB
Power Output (I _C = 8.0 mAdc, V _{CB} = 15 Vdc, f = 500 MHz)	P _{out}	30	_	mW
Common–Emitter Amplifier Power Gain ($I_C = 6.0 \text{ mAdc}, V_{CB} = 12 \text{ Vdc}, f = 200 \text{ MHz}$)	G _{pe}	11	_	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.









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